Light Emitting Diode - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5980-01-267-7901

Inclosure Material:
Metal
Overall Length:
0.136 inches
Overall Diameter:
0.062 inches
Lens Transparency:
Translucent
Function For Which Designed:
Infrared emitting
Internal Configuration:
Point contact
Joint Electronic Device Engineering Council/jedec/case Outline Designation:
Pd-570
Electrode Internally-electrically Connected To Case:
Anode
Internal Junction Configuration:
Pn
Mounting Method:
Press fit
Features Provided:
Hermetically sealed case and mounting hardware
Semiconductor Material:
Gallium arsenide
Voltage Rating In Volts Per Characteristic:
1.8 forward voltage, dc and 2.0 reverse voltage, dc
Current Rating Per Characteristic:
50.00 milliamperes source cutoff current preset
Power Rating Per Characteristic:
150.0 milliwatts small-signal input power, common-collector absolute
Color Tone Produced Per Source:
Infrared lens
Maximum Operating Tempurature Per Measurement Point:
125.0 degrees celsius ambient air
Special Features:
Connecting plate and number 20 awg. Buss wire included
Terminal Type And Quantity:
1 bonding pad and 1 case
Shelf Life:
N/a
Unit Of Measure:
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Demilitarization:

No

Fiig:

A110a0

